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CSC 347 Computer Hardware and Maintenance

Lecture 4 Data Storage

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Data Storage



- Computer data storage is a technology consisting of computer components and recording media used to retain digital data
- Storage device stores the data and instruction in a computer
 - Known as memory
- Memory is divided into large number of small parts
 - Each part is called a cell
 - Each cell can store a fixed number of bits
- Each cell has a unique number assigned to it
 - Known as address of cell
 - − Address varies from 0 to memory size − 1
 - Example: A 64k words computer memory unit has:

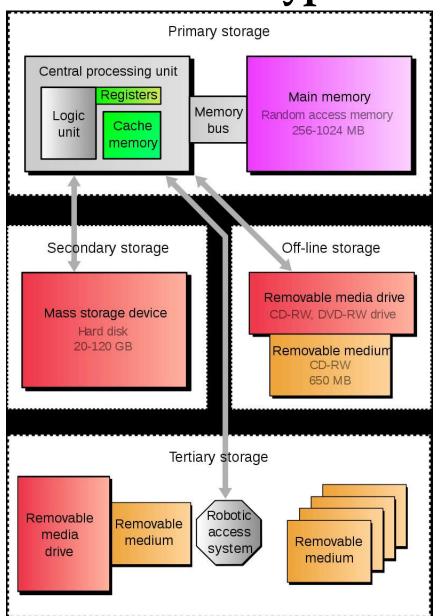
64 * *1024* = *65,536* memory locations

The address of these locations varies from 0 to 65,535



Types of Data Storage





• There are four types of storage:

- Primary Storage
 - RAM, Cache etc.
- Secondary Storage
 - Hard Disk
- Off-line Storage
 - USB flash drive, memory card etc.
- Tertiary Storage
 - Magnetic Tape, Optical disk etc.
- Others
 - Cloud storage, RAID etc.



Data Storage

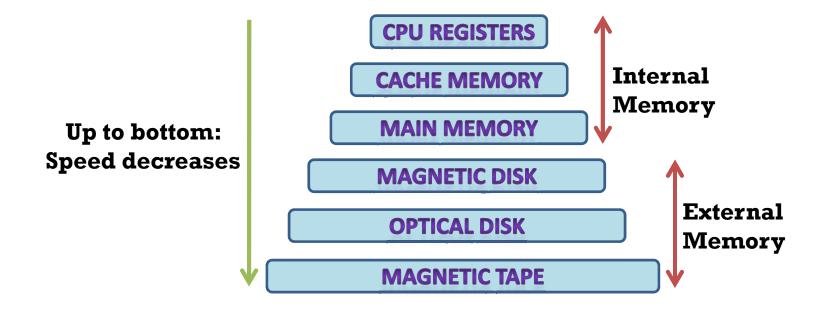


- A computer system's storage unit is ranked according to the following criteria:
 - Access Time Time required to retrieve the data
 - Storage Capacity Amount of the data that can be stored in storage unit
 - Cost per bit of storage Minimizing the cost is main goal



Memory Hierarchy





- Characteristics of Memory Hierarchy (from top to bottom) are as follows:
 - Access time by the CPU: increases
 - Frequency of access of the memory by the CPU: decreases
 - Capacity in terms of storage: increases
 - Cost per bit of storage: decreases



Memory/Storage Covered in this lecture



Primary Storage

Random Access Memory (RAM)

Secondary Storage

Hard Disk Drive (HDD)



Primary Storage Random Access Memory (RAM)



- A RAM constitutes the internal memory of CPU for storing data, program, and program result
- Also know as Read/Write memory
- Access time in RAM is independent of the address to the word, resulting:
 - Each storage location inside the memory is easy to reach as other location and takes the same amount of time
- In the form of integrated circuits that allow the stored data to be accessed in any order
- Volatile in nature
- Small in terms of its physical size, and capacity



Primary Storage Types of RAM



- Two basic types of RAM: Static RAM (SRAM), and Dynamic RAM (DRAM)
- Static RAM (SRAM)
 - Term *static* indicates that memory retains its contents as long as power remains applied
 - Chips use a matrix of 6-transistors and no capacitors
 - SRAM need not have to be refreshed on a regular basis
 - SRAM uses more chips than DRAM for the same amount of storage space
 - It's used as cache memory needs to be very fast and Small
 - It can give access time as low as 10 ns

Dynamic RAM (DRAM)

- Term *dynamic* indicates that the memory must be constantly refreshed in order for it to maintain the data
 - This is done by placing the memory on a refresh circuit that rewrites the data several hundred times per second
- All DRAMs made up of memory cells
 - These cells are composed one capacitor and one transistor
- DRAM memory access time is 60 ns



Primary Storage SRAM Design



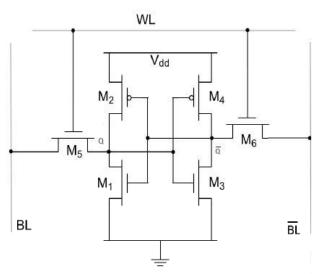


Figure2. A six-transistor CMOS SRAM cell

- A typical SRAM cell is made up of six MOSFETs (Metal Oxide Semiconductor Field Effect Transistors)
- Each bit in an SRAM is stored on four transistors (*M1*, *M2*, *M3*, *M4*) that form two cross-coupled inverters
- This storage cell has two stable states which are used to denote *0* and *1*
- Two additional access transistors serve to control the access to a storage cell during read and write operations
- Access to the cell is enabled by the word line (WL) which controls two access transistors M_5 and M_6 which, in turn, control whether the cell should be connected to the bit lines: \overline{BL} and BL
 - They are used to transfer data for both read and write operations



Primary Storage SRAM Design



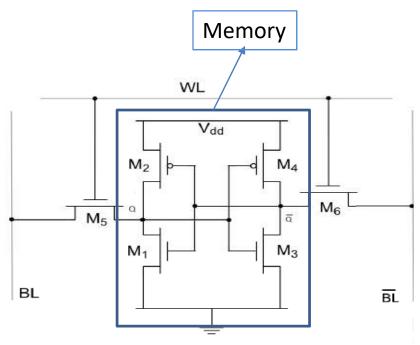
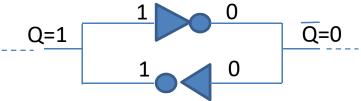


Figure2. A six-transistor CMOS SRAM cell

Simplified circuit (two inverters are connected)



M5 and M6 are the access transistors

- If the output lines (----) is connected to something, Read or Write is possible in the memory. BL and BL are act as these lines.
- To access these lines, M5 and M6 access transistors are used
- If WL = 1, M5 and M6 are on that means BL and BL lines are accessible resulting Read and Write are possible
- If WL = 0, access is off and memory is in hold state
- BL and BL are act as input lines When something need to Write in to memory
- BL and BL are act as output lines When something need to read from memory
- Pre-charged capacitors are used for read and write (not shown in figure)

Basic Not gate has been changed to CMOS inverter







- An SRAM cell has three different states:
 - Standby (the circuit is idle)
 - Reading (the data has been requested) or
 - writing (updating the contents)







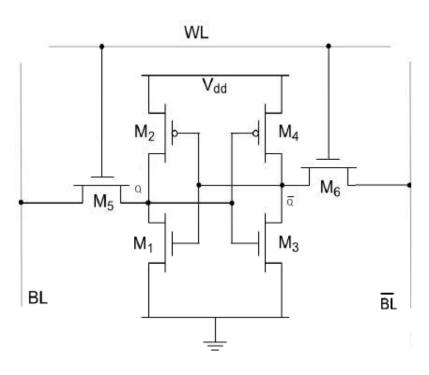


Figure2. A six-transistor CMOS SRAM cell

- If the word line is not asserted, the access transistors M_5 and M_6 disconnect the cell from the bit lines
- The two cross-coupled inverters formed by $M_1 M_4$ will continue to reinforce each other as long as they are connected to the supply



Primary Storage



SRAM Operation: Reading

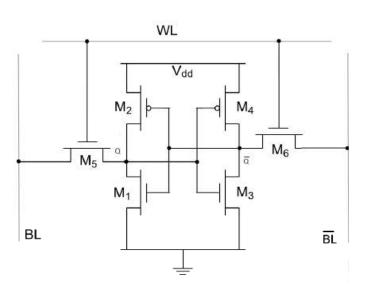


Figure2. A six-transistor CMOS SRAM cell

- During the read time in SRAM, Memory Should hold some value
 - Suppose Memory: Q = 1 and $\overline{Q} = 0$
- Bit line (BL) and **BL** are going to be used to read
- When the Word Line (WL) = 1, access transistors are on
- While reading, BL and \overline{BL} are the output lines
- Precharged VDD
- Check the voltage difference at the both side:
 - Q=1 & load-voltage in BL=VDD; no voltage difference
 - \overline{Q} =0 & load-voltage in \overline{BL} =VDD; voltage difference
 - **BL** Voltage is decreased
- Send the found values of BL and \overline{BL} to a sense amplifier
 - Sense amplifier will sense which line has the higher voltage and thus determine whether there is 1 or 0 stored
- When the \overline{BL} voltage decreases output value is 1
- Memory read is successful
- When in Memory: Q = 0 and $\overline{Q} = 1$, What happens?



Primary Storage



SRAM Operation: Write Operation

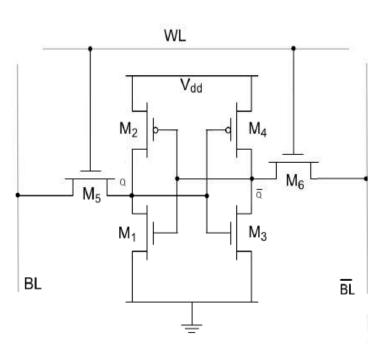


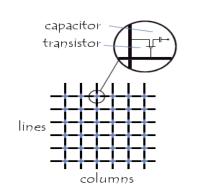
Figure2. A six-transistor CMOS SRAM cell

- Suppose memory value $\mathbf{Q} = \mathbf{0}$ and $\overline{\mathbf{Q}} = 1$
- Bit line (BL) and **BL** are going to be used to write
- When the Word Line (WL) = 1, BL and \overline{BL} are ready to access
- To write into memory, BL and \overline{BL} are input lines, \overline{BL} is force to ground because
 - \overline{Q} = 1 and \overline{BL} is ground; Voltage difference
- When **BI** voltage is decreasing, M1 and M2 transistors are going to be affected
- If voltage < threshold voltage of M1
 - M1 is Off
 - M2 is On; Q = 1
- It can be easily seen that Q was 0, but now Q is 1; resulting write operation is successful in memory









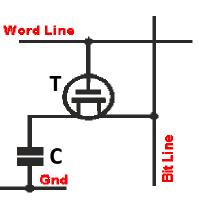


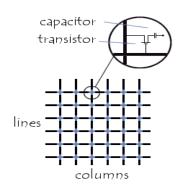
Figure3. DRAM Memory cell

- DRAM memory technology has MOS technology at the heart of the design, fabrication and operation
- DRAM memory cell uses a capacitor to store each bit of data and a transfer device a MOSFET (Metal Oxide Semiconductor Field Effect Transistor) that acts as a switch
- The level of charge on the memory cell capacitor determines whether that particular bit is a logical "1" or "0"
 - Presence of charge in the capacitor indicates a logic "1" and
 - Absence of charge indicates a logical "0"
- Two lines are connected to each dynamic RAM cell the Word Line (W/L) and the Bit Line (B/L) connect as shown so that the required cell within a matrix can have data read or written to it









Read Operation:

Write Operation:

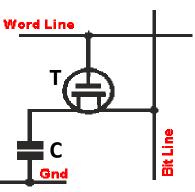


Figure3. DRAM
Memory cell

- When the word line is selected, the transistor turns on and the charge stored on the capacitor is fed out onto a bit line and to a sense amplifier
- The sense amplifier compares the capacitor voltage to a reference value and determines if the cell contains logic 1 or logic 0
- The read out from the cell discharges the capacitor, which must be stored to complete the operation
- A voltage signal is applied to the bit line
 - a high voltage represents 1, and
 - a low voltage represents 0
- A signal is then applied to the word line, allowing a charge to be transferred to the capacitor



Secondary Storage



- It is not directly accessible by the CPU
- Computer usually uses its input/output channels to access this type of storage and transfers the desire data using intermediate area in primary storage
- Secondary storage characteristics
 - Media
 - Capacity
 - Storage devices
 - Access speed
- Terminology
 - Reading: is the process of accessing information
 - Writing: is the process of saving information





Secondary Storage Hard Disk

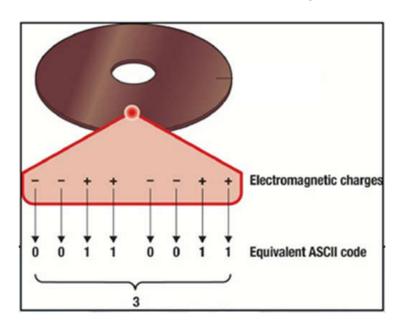
- Hard Disk Drive (HDD), it is the main and usually largest data storage device in a computer (usually, 160GB to 15TB)
- Hard disk speed is the speed at which content can be read and written on a hard disk.
- A HDD unit comes with a set rotation speed varying from 5400 to 7200 rpm (for desktop and laptop)
- Disk access time is measured in milliseconds





- Hard disks save files by altering the magnetic charges of the disk's surface to represent 1s and 0s
- Hard disks retrieve data and programs by reading these charges from the magnetic disk
- Characters are represented by positive (+) and negative (-) charges using the ASCII, EBCDIC, or Unicode binary code













Internal Hard Disk



Keywords	Internal Hard Disk	External Hard Disk
Portability	No	Yes
Price	Less expensive	More Expensive
Speed	Fast	Slow
Size	Big	Small
Special Installation	Required	Does not required



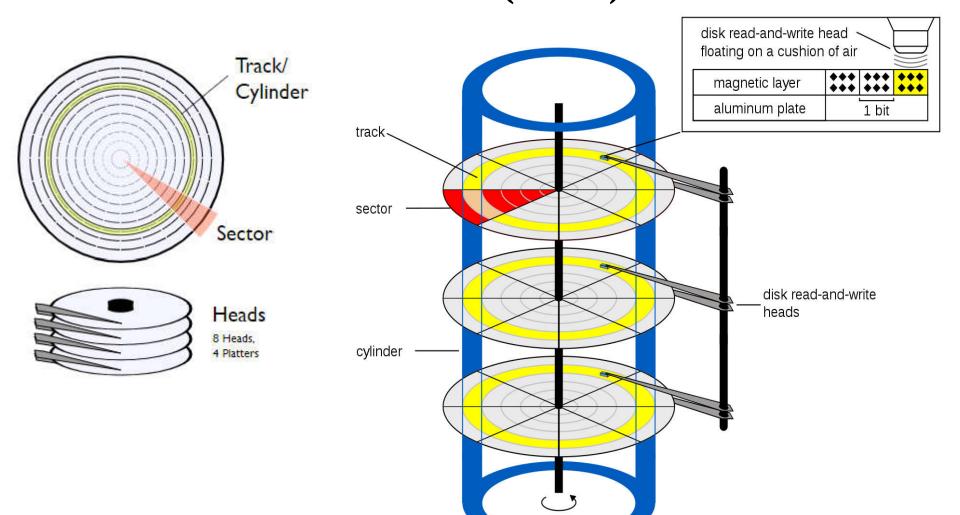


Components of a Hard Drive

- **Platters** are multiple hard metal surfaces that are stacked one on top of another contained in the hard drive
- **Read/Write Heads** write and read 1s and 0s to and from hard drive surface
 - A **Head Crash** occurs when a read/write head touches the hard drive platter
- **Track** is a concentric circle on a hard drive platter
- **Sectors** Each track is divided into sectors which contains 512 bytes of data
 - o **ZBR (Zone Bit Recording)** efficiently uses the hard drive surface by placing more sectors on the outer tracks than on the inner tracks
 - o **Interleaving** is a method of numbering sectors for the most efficient transfer of data between hard drive and controller. Hard drives normally use 1:1 interleave
- Cylinder runs through each track of a stack of platters
 - Cylinders are necessary to differentiate files stored on same track and sector of different platters
- When a hard disk is formatted, tracks, sectors, and cylinders are assigned



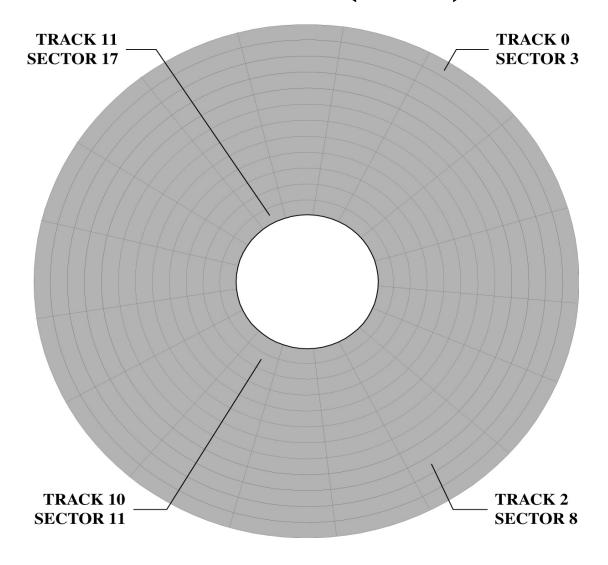




Hard Drive Geometry



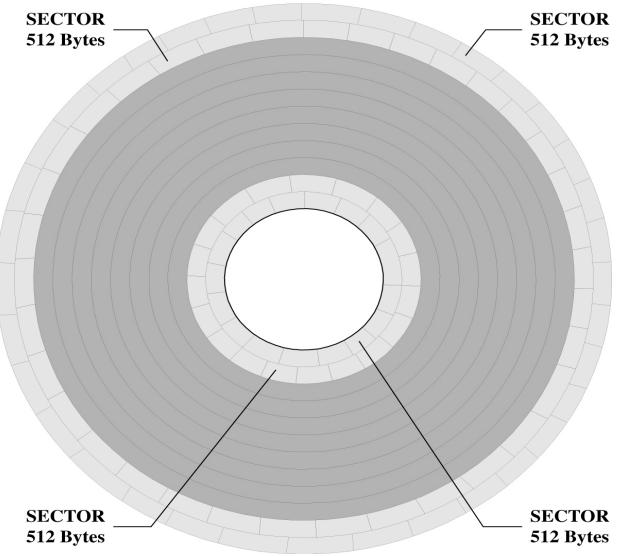










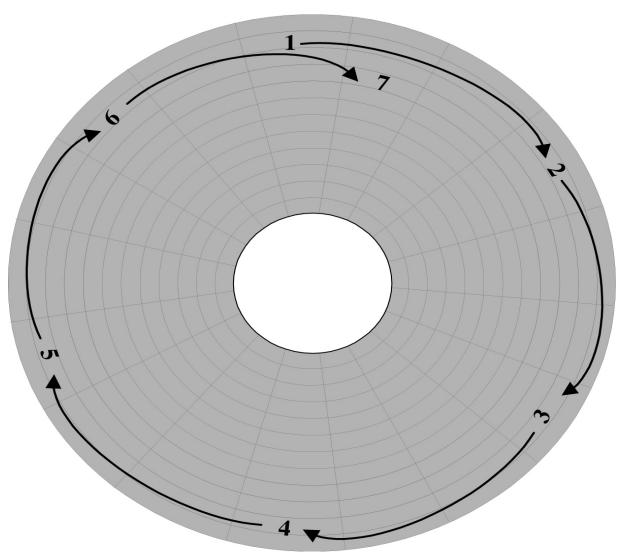


Zone Bit Recording Sectors

Lecture 4: Data Storage (Secondary Storage)



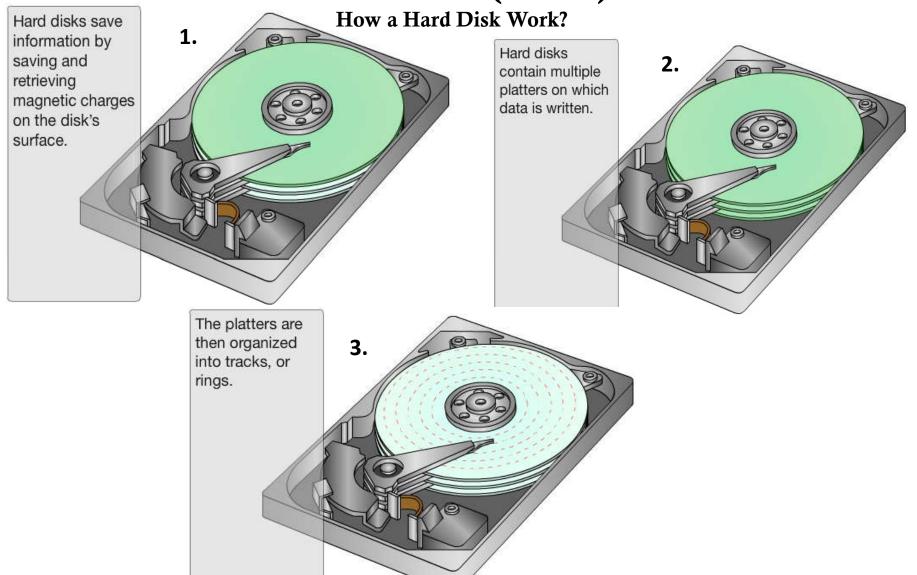




3:1 Interleaving

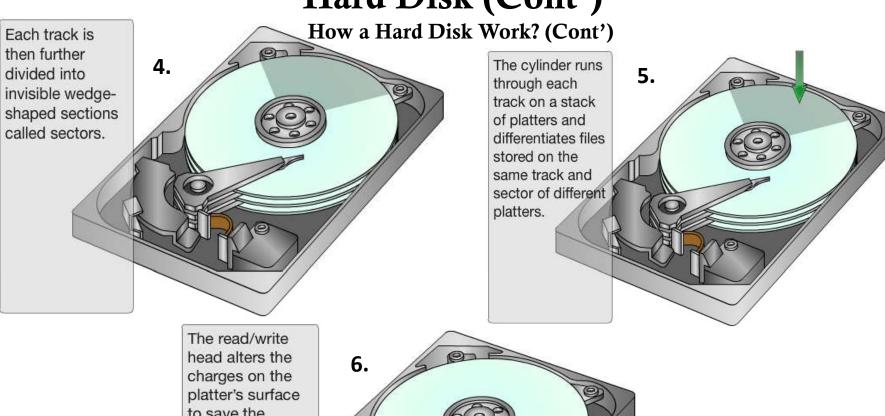


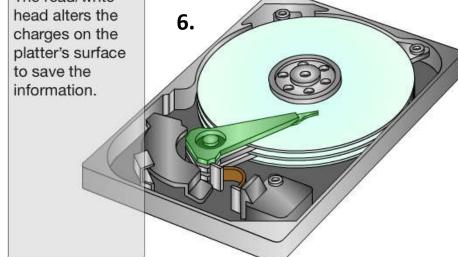
















- Hard disks are sensitive instruments
- Their read/write heads ride on a cushion of air about 0.000001 inch thick.
 - It is so thin that a smoke particle, fingerprint, dust, or human hair could cause what is known as a head crash

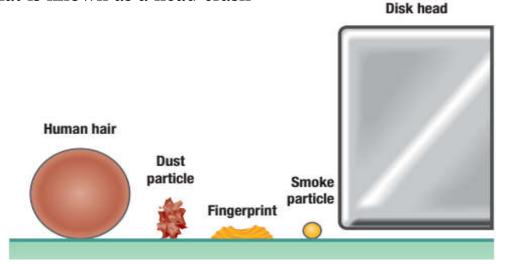


Figure 3. Materials that can cause a head crash

- A head crash occurs when a read/write head makes contact with the hard disk's surface or with particles on its surface
- A head crash is a disaster for a hard disk



Secondary Storage Hard Disk (Cont') **Hard-drive Partitioning**



Extended partition

E:

logical drives

D:

Partitioning divides a hard drive so that the computer system sees

Primary partition

more than one drive



- The **Primary Partition** is the first detected drive on the hard drive
- The Extended Partition is a hard drive division
- Logical drives divides the extended partition into separate units which appear as separate drive letters
- The boot sector called MBR (Master Boot Record) is the first sector of a hard drive (Cylinder 0, head 0, sector 1)
 - it contains the main partition and the code, called the Boot Loader, which when loaded in to the memory, will allow the system to boot up
 - After it is loaded into memory, this program will determine from which system partition to boot, and will start the program (called the **bootstrap**), which will start up operating system present on that partition





Hard-drive Partitioning (Cont')

How Drive Letters Are Assigned:

- The order in which the partitions are assigned drive letters depends on three factors:
 - The number of hard drives
 - The type of partitions on the hard drives
 - The operating system
- The first floppy drive detected is assigned drive letter A:
- The second floppy drive detected is assigned drive letter B:
- The first hard drive primary partition detected receives drive letter C:
- Drive letters assigned after letter C: are dependent upon the operating system installed





Hard-drive Partitioning (Cont')

- A File System defines how data is stored on a drive.
 - FAT (File Allocation Table) is a method of organizing a computer's file system
 - FAT16 file system is supported by DOS, Windows 9x, NT, 2000, and XP
 - FAT32 file system used by Windows 95 Service Release 2, Windows 98,
 Windows 2000, XP and so on that supports hard drives up to 2TB in size
 - NTFS (NT File System) file system used with Windows NT, Window XP, 7, 8, 9, 10
 - Linux Ex2, Ex3, Ex4 and beyond for Linux





Preventive Maintenance for Hard Drives

- Preventive Maintenance will prolong the life of HDD
 - CHKDSK is a program that locates clusters disassociated from data files
 - Lost Clusters are sectors on a disk that the file allocation table cannot associate with any file or directory
 - SCANDISK is a software program used to detect and repair lost clusters
 - Disk Cleanup utility helps free up hard drive space by emptying the Recycle Bin, removing temporary files, etc.
 - Defragmentation is the process of placing files in contiguous sectors. This allows for faster hard disk access of files









Disk caching

- Provides a temporary high- speed holding area
 between a secondary storage device and the CPU
 - ➤ Improves performance by anticipating data needs and reducing time to access data from secondary storage

Redundant Arrays of Inexpensive Disks (RAID)

- Several inexpensive hard-disk drives are connected together
 - ➤ Improves performance by providing expanded storage, fast access, and high reliability

File compression and decompression

- Files compressed before storing and then decompressed before being used again
 - ➤ Improves performance through efficient storage



Secondary Storage Hard Disk (Cont') Redundant Arrays of Inexpensive Disks (RAID)

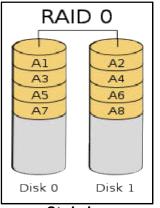


- Storage is an important part of fault tolerance
- A disk failure results in data loss that is not desired in any organization and therefore, data loss prevention is required
- RAID can be one of the best ways to prevent data loss
 - The data is copied on multiple disk
 - Different RAID Levels: RAID 0 (Striping), RAID 1 (Mirroring), RAID 2 (Bit-level striping with Hamming code for error correction), RAID 3 (Byte-level striping with dedicated parity), RAID 4 (Block-level striping with dedicated parity), RAID 5 (Block-level striping with distributed parity), RAID 6 (Block-level striping with double distributed parity), RAID 10 (Striping + Mirroring), and so on

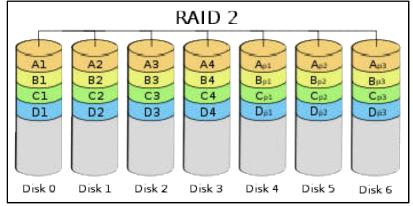


Different levels of RAID





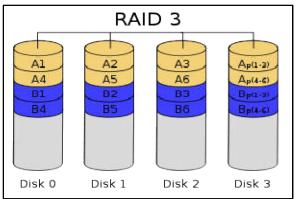
RAID 1 A1 Al A2 A2 **A3** A3 A4 A4 Disk 0 Disk 1

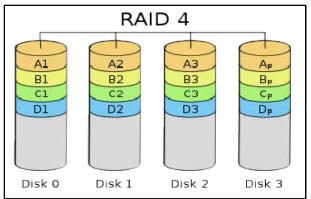


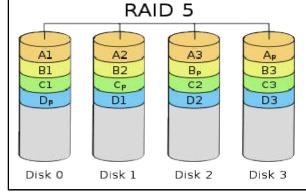
Striping

Mirroring

Bit-level striping







Byte-level striping with dedicated parity

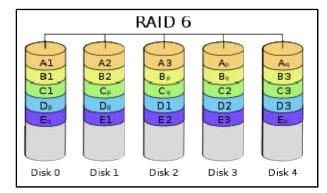
Block-level striping with dedicated parity

Block-level striping with distributed parity

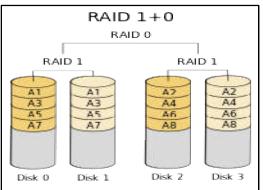
Commonly used

RAID Levels are

RAID 0, 1, 5, 6, 10



Block-level striping with double distributed parity



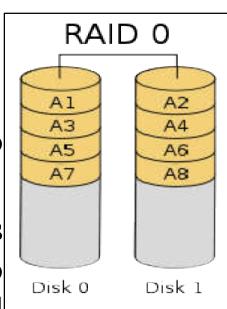
Combining mirroring and striping





Redundant Arrays of Inexpensive Disks (RAID)

- It splits data among two or more disks.
- Provides good performance.
- Lack of data redundancy means there is no fail over support with this configuration.
- In the diagram to the right, the odd blocks are written to disk 0 and the even blocks to disk 1 such that A1, A2, A3, A4, ... would be the order of blocks read if read sequentially from the beginning.
- Used in read only Network File System (NFS) systems and gaming systems.



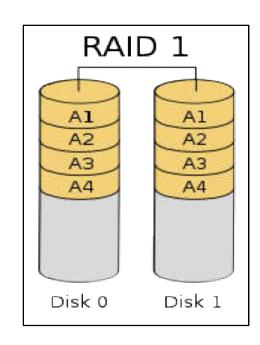


Secondary Storage Hard Disk (Cont') Redundant Arrays of Inexpensive Disks (RAID)



RAID 1

- RAID1 is 'data mirroring'.
- Two copies of the data are held on two physical disks, and the data is always identical.
- Twice as many disks are required to store the same data when compared to RAID 0.
- Array continues to operate so long as at least one drive is functioning.



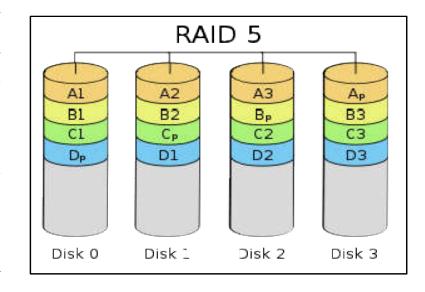






Redundant Arrays of Inexpensive Disks (RAID)

- RAID 5 is an ideal combination of good performance, good fault tolerance and high capacity and storage efficiency.
- An arrangement of parity and CRC to help rebuilding drive data in case of disk failures.
- "Distributed Parity" is the key word here.

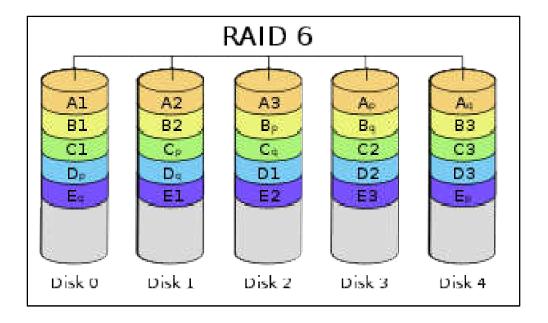








- It is seen as the best way to guarantee data integrity as it uses double parity.
- It has a drawback though of longer write time.









- Combines RAID 1 and RAID0.
- Which means having the pleasure of both good performance and good failover handling.
- Also called 'Nested RAID'.
- Benefits from the fault tolerance of RAID 1 and The Speed of RAID 0

